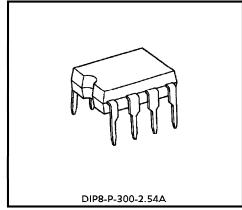
TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA8026P

FLASHER CONTROLLER

The TA8026P is designed as an automotive flasher controller. It can issue a rapied-flashing warning when a lamp failure occurs.

It operates accurately in wide ranges of supply voltages and operating temperatures. It incorporates an accurate reference voltage circuit which compensates for lamp current characteristic variations due to supply voltage changes.

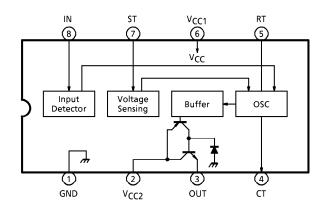


Weight: 0.45g (Typ.)

FEATURES

- Large output current : IOUT = 300mA (Max.)
- Low standby current : $I_{CC} = 1.0 \text{mA}$ (Typ.)
- Reference voltage characterized by small temperature drift.
- Built-in circuit that compensates for variations in lamp voltage characteristics.
- Output from combination of PNP and NPN transistors with suppression diode.
- Wide operating temperature : Ta = -40 to $110^{\circ}C$
- DIP-8pin.

BLOCK DIAGRAM AND PIN LAYOUT



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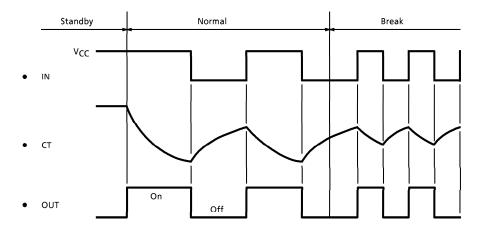
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PIN DESCRIPTION

PIN No.	SYMBOL	DESCRIPTION
1	GND	Grounded.
2	V _{CC2}	Power supply pin (2).
3	ОИТ	Open-emitter output of complementary combination of PNP and NPN transistors.
4	СТ	A capacitor is connected between V_{CC} and CT. This layout determines the flashing interval of the flasher.
5	RT	A resistor is connected between RT and CT. This layout determines the flashing interval of the flasher.
6	V _{CC1}	Power supply pin (1).
7	ST	Current detection pin. The lamp current is detected through a shunt resistor connected between V _{CC1} and ST.
8	IN	Detection pin for lamp operation.

TIMING CHART



MAXIMUM RATINGS (Ta = 25°C)

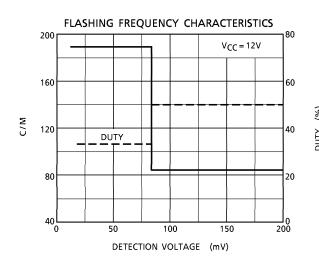
CHARACTERISTIC	SYMBOL	RATING	UNIT
Power Supply Voltage	Vcc	28	V
Power Dissipation	P_{D}	300 *	mW
Output Current	IOUT	300	mA
Input Voltage	VIN	−0.3~V _{CC}	V
Operating Temperature	T _{opr}	-40∼110	°C
Storage Temperature	T _{stg}	- 55∼150	°C
Lead Temperature·time	T _{sol}	260 (10s)	°C

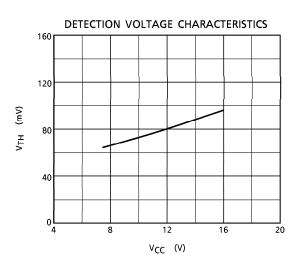
^{*} Ta≦110°C

ELECTRICAL CHARACTERISTICS ($V_{CC} = 12V$, $Ta = -40 \sim 110^{\circ}C$)

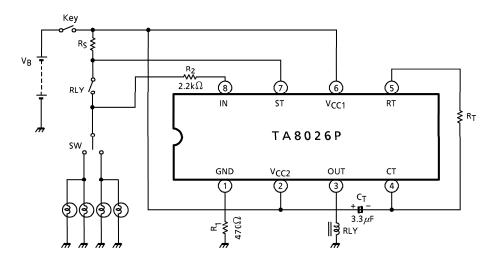
CHARACTERISTIC	SYMBOL	PIN	TEST CIR- CUIT		MIN.	TYP.	MAX.	UNIT
Operating Voltage	V _{opr}	Vcc	_	_	6	_	18	V
	lcc	GND	_	Standby, Ta = 25°C	0.6	0.9	1.4	mA
Power Supply Current			_	Output on, Ta = 25°C	2.5	4.0	6.0	
Output Voltage	Voн	OUT	_	$R_L = 82\Omega$		_	1.3	V
Leakage Current	ILEAK	OUT	_	V _{OUT} = 0V	- 100	_	_	μA
		CT	_	$V_{IN} = V_{CC} \sim V_{CC} - 5V$	- 10	_	10	μΑ
Innut Current	lisi	ST	_	V _{IN} = V _{CC}	- 10	_	10	
Input Current	lIN	IN	_	V _{IN} = 12V		_	20	
			_	V _{IN} = 0V	– 1.5	- 2.5	- 3.5	mΑ
Innut Valtage	V _{IL}	IN	_	_		_	0.4	×Vcc
Input Voltage	VIH		_	_	0.6	_	_	
	VTH	ST	_	V _{CC} = 9V	63	71	78	mV
			_	V _{CC} = 12V	75	82	89	
Detection Voltage			_	V _{CC} = 15V	87	95	103	
	⊿V _{TH} / T		_	_	- 60	_	60	μ V / °C
	Δντη/Δνςς		_	_	2.7	3.3	3.9	mV/V
Flashing Interval	_	OUT		$C_T = 3.3 \mu F, R_T = ADJ *$	690	706	723	ms
Flashing Interval	_	OUT			315	324	333	
(At fail detection)						324		
On Duty		OUT			45	50	55	%
On Duty (At fail detection)	_	OUT			30	_	50	

^{*} Adjust the flashing interval to 706ms by changing R_T while keeping $C_T = 3.3 \mu F$ at room temperature.





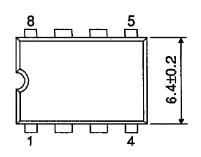
EXAMPLE OF APPLICATION CIRCUIT

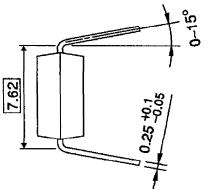


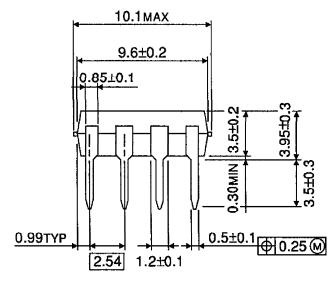
Note : The tolerance of R $_1$ and R $_2$ is within $\,\pm\,5\%\,.$

OUTLINE DRAWING

DIP8-P-300-2.54A Unit: mm







Weight: 0.45g (Typ.)